

FFPF10UP20S

10 A, 200 V, Ultrafast Diode

Description

The FFPF10UP20S is an ultrafast diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder and UPS application.

Features

- Ultrafast Recovery $t_{rr} = 35 \text{ ns}$ (@ $I_F = 1 \text{ A}$)
- Max Forward Voltage, $V_F = 1.15 \text{ V}$ (@ $T_C = 25^\circ\text{C}$)
- Reverse Voltage, $V_{RRM} = 200 \text{ V}$
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Power Switching Circuits, SMPS
- Output Rectifiers
- Freewheeling Diodes

ABSOLUTE MAXIMUM RATINGS

$T_C = 25^\circ\text{C}$ unless otherwise noted

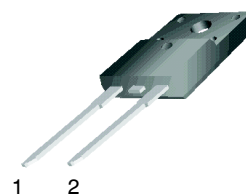
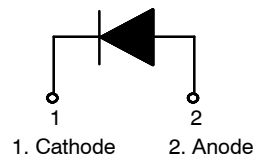
Symbol	Parameter	Rating	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	200	V
V_{RWM}	Working Peak Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 25^\circ\text{C}$	10	A
I_{FSM}	Non-repetitive Peak Surge Current 60 Hz Single Half-Sine Wave	100	A
T_J, T_{STG}	Operating Junction and Storage Temperature	-65 to +175	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



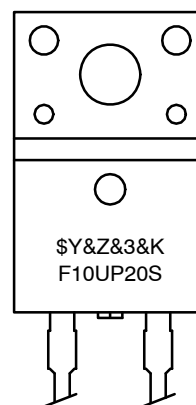
ON Semiconductor®

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TO-220, 2-Lead
CASE 221AS

MARKING DIAGRAM



\$Y	= ON Semiconductor Logo
&Z&3	= Data Code (Year & Week)
&K	= Lot
F10UP20S	= Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFPF10UP20S

THERMAL CHARACTERISTICS $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	4.3	$^\circ\text{C}/\text{W}$

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF10UP20STU	F10UP20S	TO-220F-2L	Tube	N/A	N/A	50

ELECTRICAL CHARACTERISTICS $T_C = 25^\circ\text{C}$ unless otherwise noted

Parameter	Conditions	Min.	Typ.	Max.	Unit
V_F (Note 1)	Forward Voltage $I_F = 10\text{ A}$ $I_F = 10\text{ A}$ $T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$	– –	– –	1.15 1.10	V
I_R (Note 1)	Reverse Current @ rated V_R $T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	– –	– –	100 500	μA
t_{rr} I_{rr} Q_{rr}	Reverse Recovery Time Reverse Recovery Current Reverse Recovery Charge ($I_F = 6\text{ A}$, $di_F/dt = 200\text{ A}/\mu\text{s}$, $V_R = 130\text{ V}$) $T_C = 25^\circ\text{C}$	– – –	32 1.65 24.4	– – –	ns A nC
W_{AVL}	Avalanche Energy ($L = 40\text{ mH}$)	5	–	–	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse Width = 300 μs , Duty Cycle = 2%

Test Circuit and Waveforms

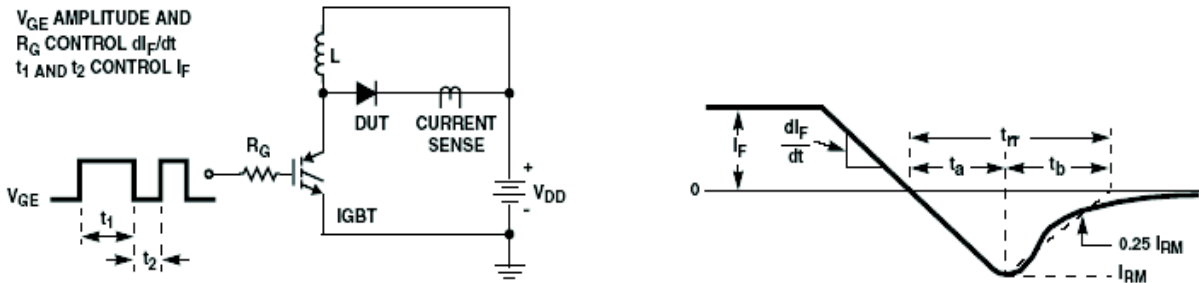


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

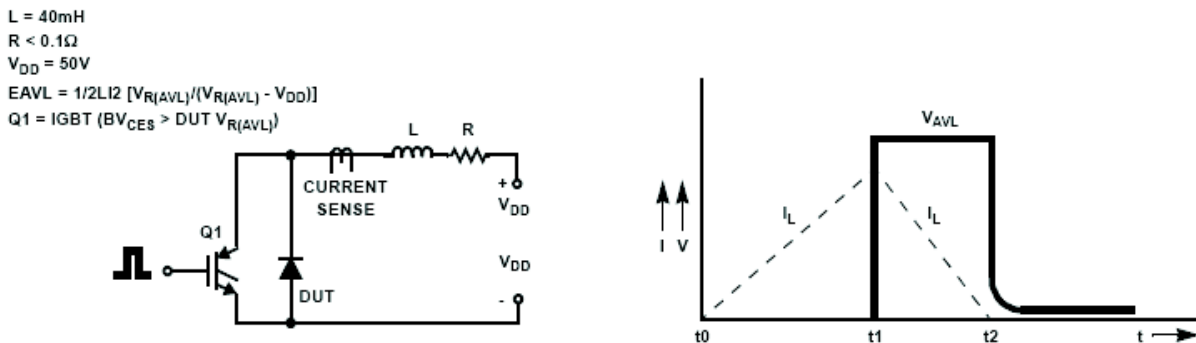


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

TYPICAL CHARACTERISTICS

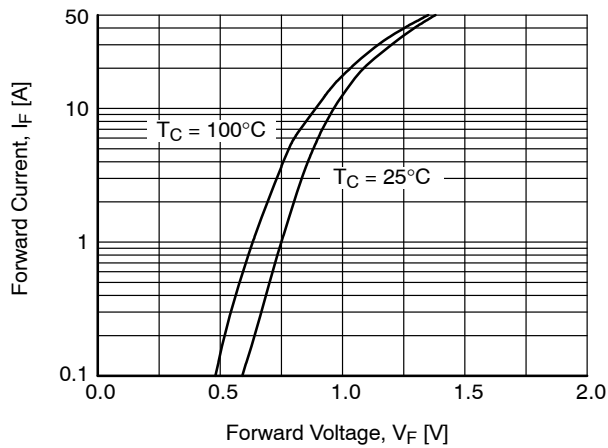


Figure 3. Typical Forward Voltage Drop vs. Forward Current

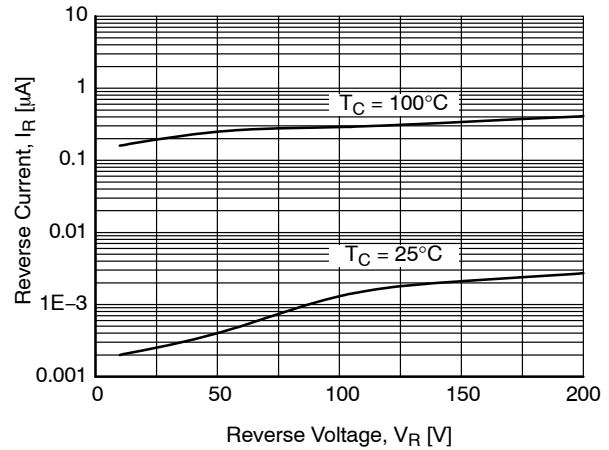


Figure 4. Typical Reverse Current vs. Reverse Voltage

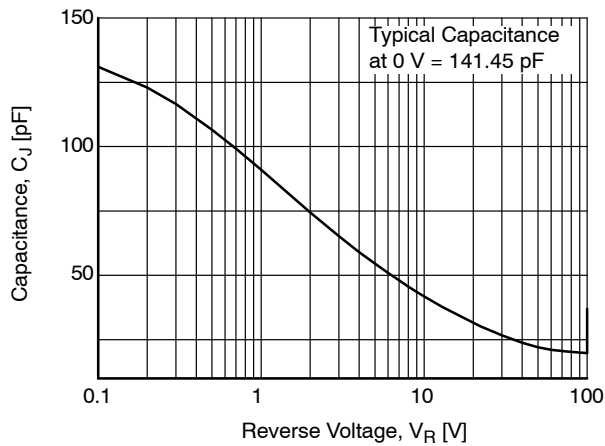


Figure 5. Typical Junction Capacitance

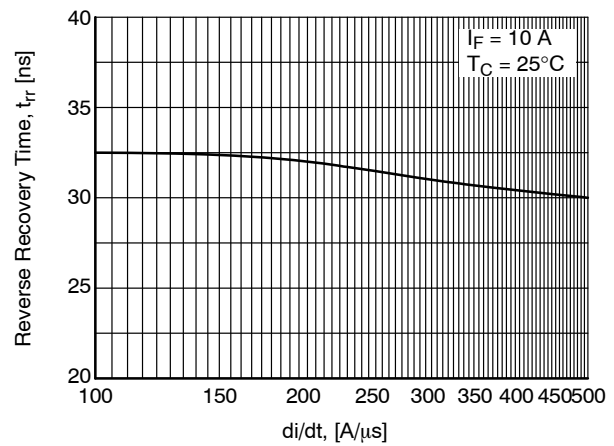


Figure 6. Typical Reverse Recovery Time vs. di_F/dt

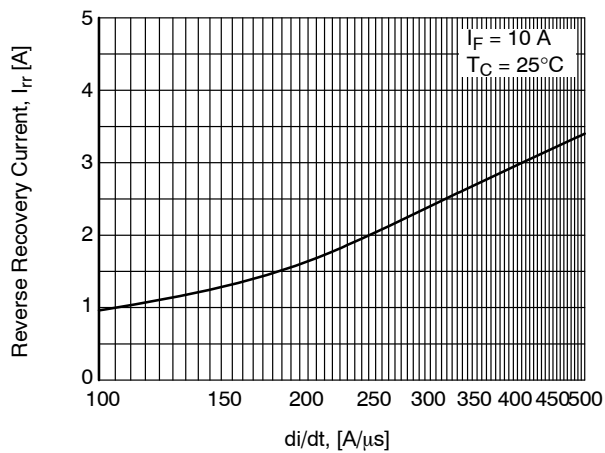


Figure 7. Typical Reverse Recovery Current vs. di_F/dt

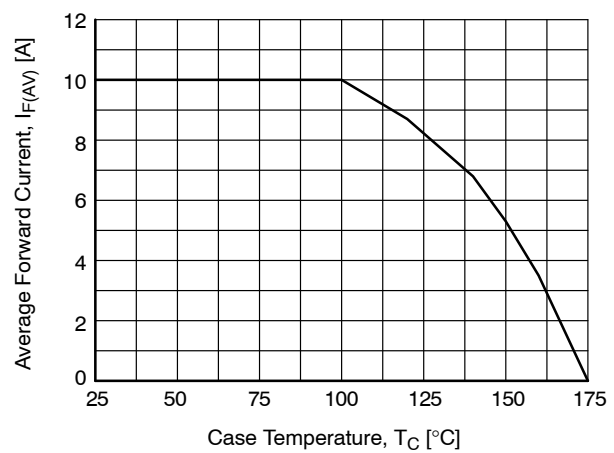
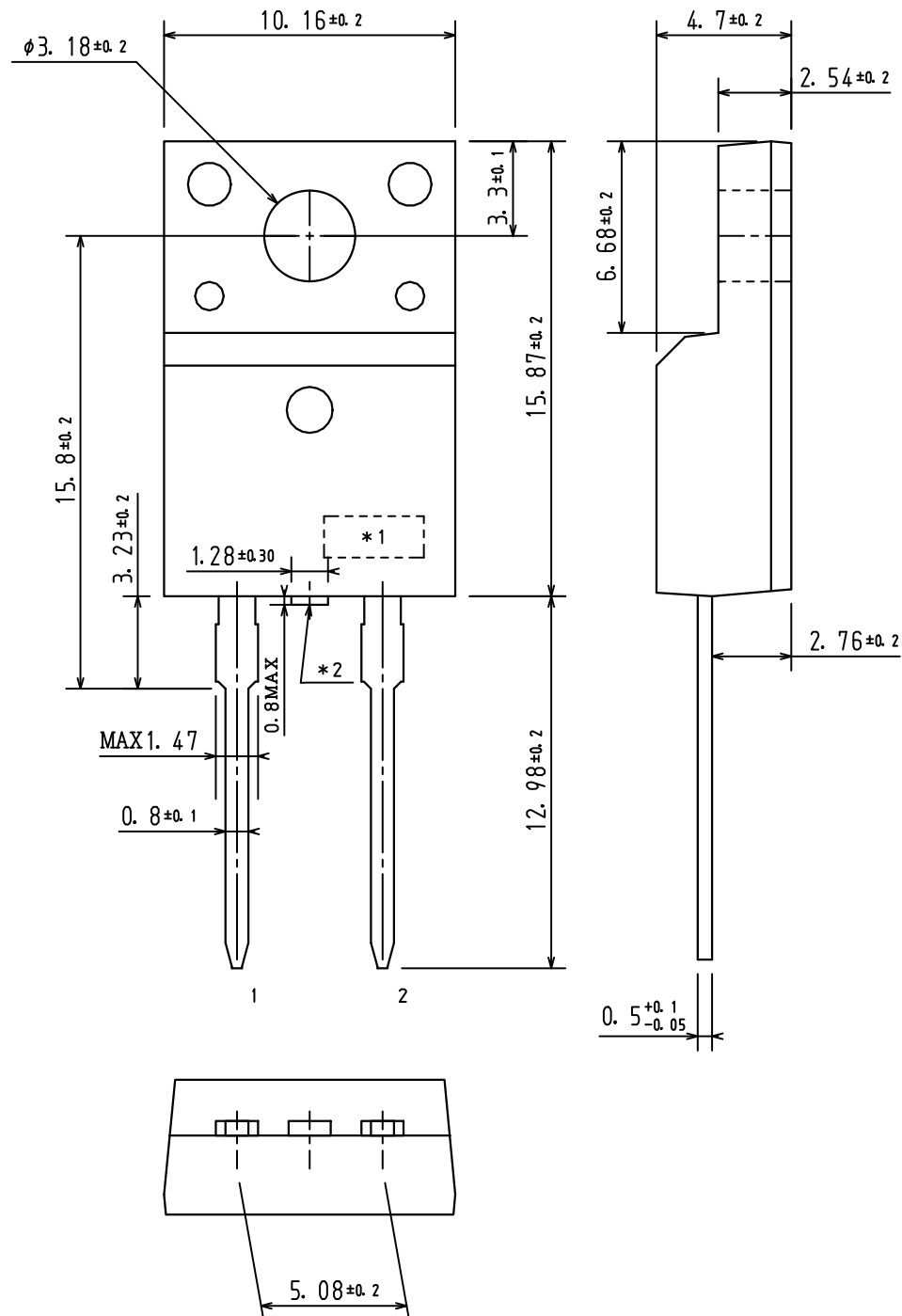


Figure 8. Forward Current Derating Curve

TO-220 Fullpack, 2-Lead / TO-220F-2FS
CASE 221AS
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DESCRIPTION:	TO-220 FULLPACK, 2-LEAD / TO-220F-2FS	PAGE 1 OF 1

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